

# SHINDENGEN

## Schottky Rectifiers (SBD)

Dual

**S20SC9M**

**90V 20A**

### FEATURES

- $T_j = 150^\circ\text{C}$
- $P_{RRSM}$  avalanche guaranteed
- Small  $\theta_{jc}$
- High current capacity

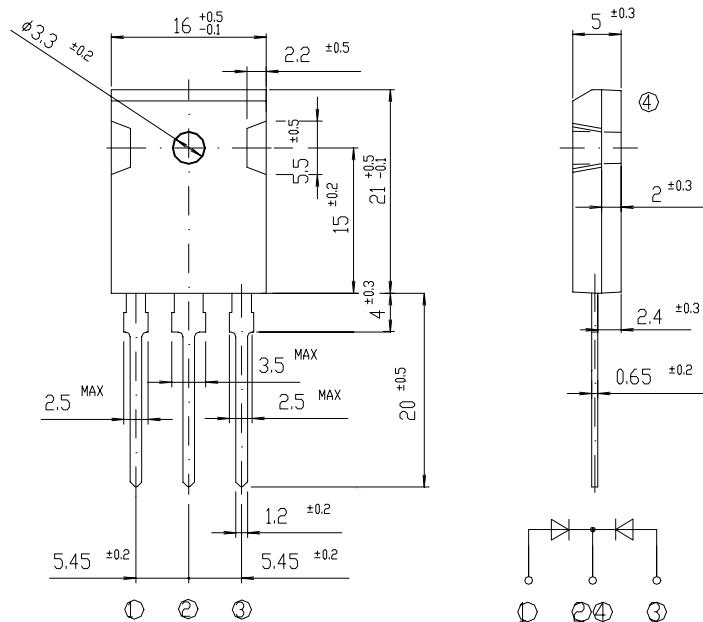
### APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

### OUTLINE DIMENSIONS

Case : MTO-3P

Unit : mm



### RATINGS

#### ● Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$ )

| Item                                  | Symbol     | Conditions  | Ratings   | Unit             |
|---------------------------------------|------------|---|-----------|------------------|
| Storage Temperature                   | $T_{stg}$  |   | -40 ~ 150 | $^\circ\text{C}$ |
| Operating Junction Temperature        | $T_j$      |   | 150       | $^\circ\text{C}$ |
| Maximum Reverse Voltage               | $V_{RM}$   |   | 90        | V                |
| Repetitive Peak Surge Reverse Voltage | $V_{RRSM}$ | Pulse width 0.5ms, duty 1/40  | 100       | V                |
| Average Rectified Forward Current     | $I_o$      | 50Hz sine wave, R-load, Rating for each diode $I_o/2$ , $T_c=125^\circ\text{C}$ | 20        | A                |
| Peak Surge Forward Current            | $I_{FSM}$  | 50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j=25^\circ\text{C}$       | 200       | A                |
| Repetitive Peak Surge Reverse Power   | $P_{RRSM}$ | Pulse width 10 $\mu\text{s}$ , Rating of per diode, $T_j=25^\circ\text{C}$      | 660       | W                |
| Mounting Torque                       | $T_{OR}$   | (Recommended torque: 0.5N·m)  | 0.8       | N·m              |

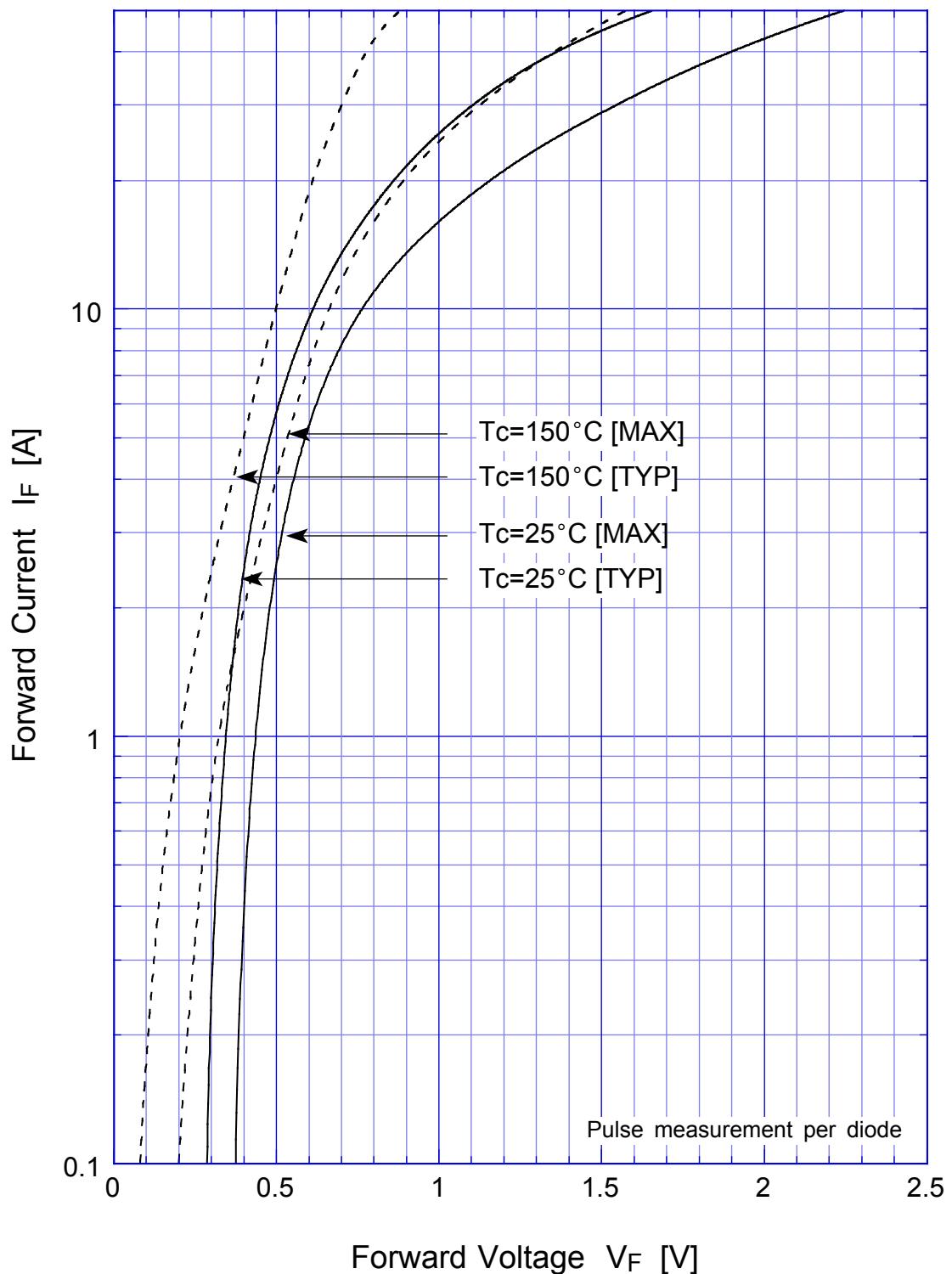
#### ● Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$ )

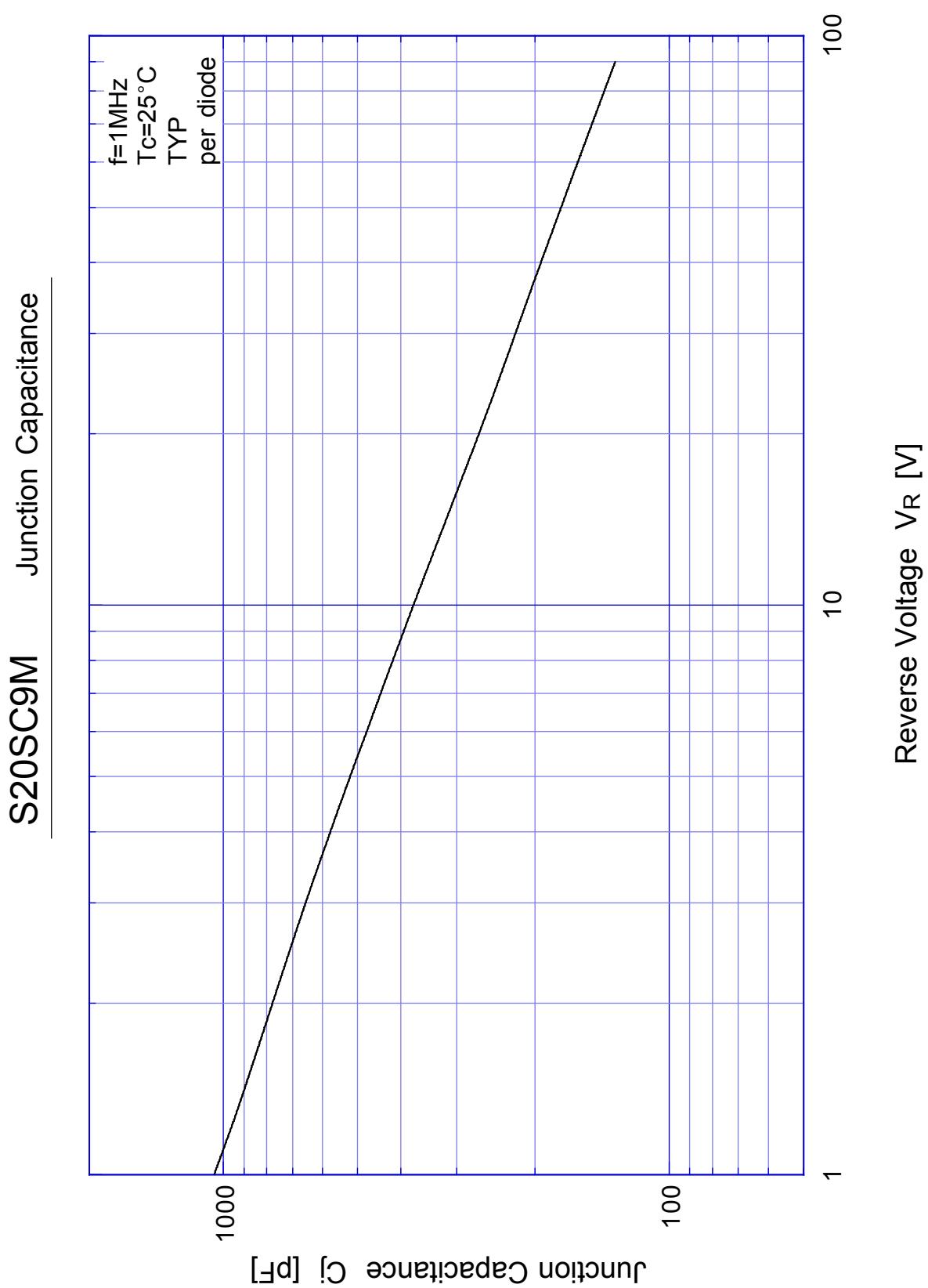
| Item                 | Symbol        | Conditions  | Ratings   | Unit                      |
|----------------------|---------------|---|-----------|---------------------------|
| Forward Voltage      | $V_F$         | $I_F=10\text{A}$ , Pulse measurement, Rating of per diode | Max. 0.75 | V                         |
| Reverse Current      | $I_R$         | $V_R=V_{RM}$ , Pulse measurement, Rating of per diode     | Max. 10   | mA                        |
| Junction Capacitance | $C_j$         | $f=1\text{MHz}$ , $V_R=10\text{V}$ , Rating of per diode  | Typ. 370  | pF                        |
| Thermal Resistance   | $\theta_{jc}$ | junction to case  | Max. 1.0  | $^\circ\text{C}/\text{W}$ |

# S20SC9M

---

## Forward Voltage

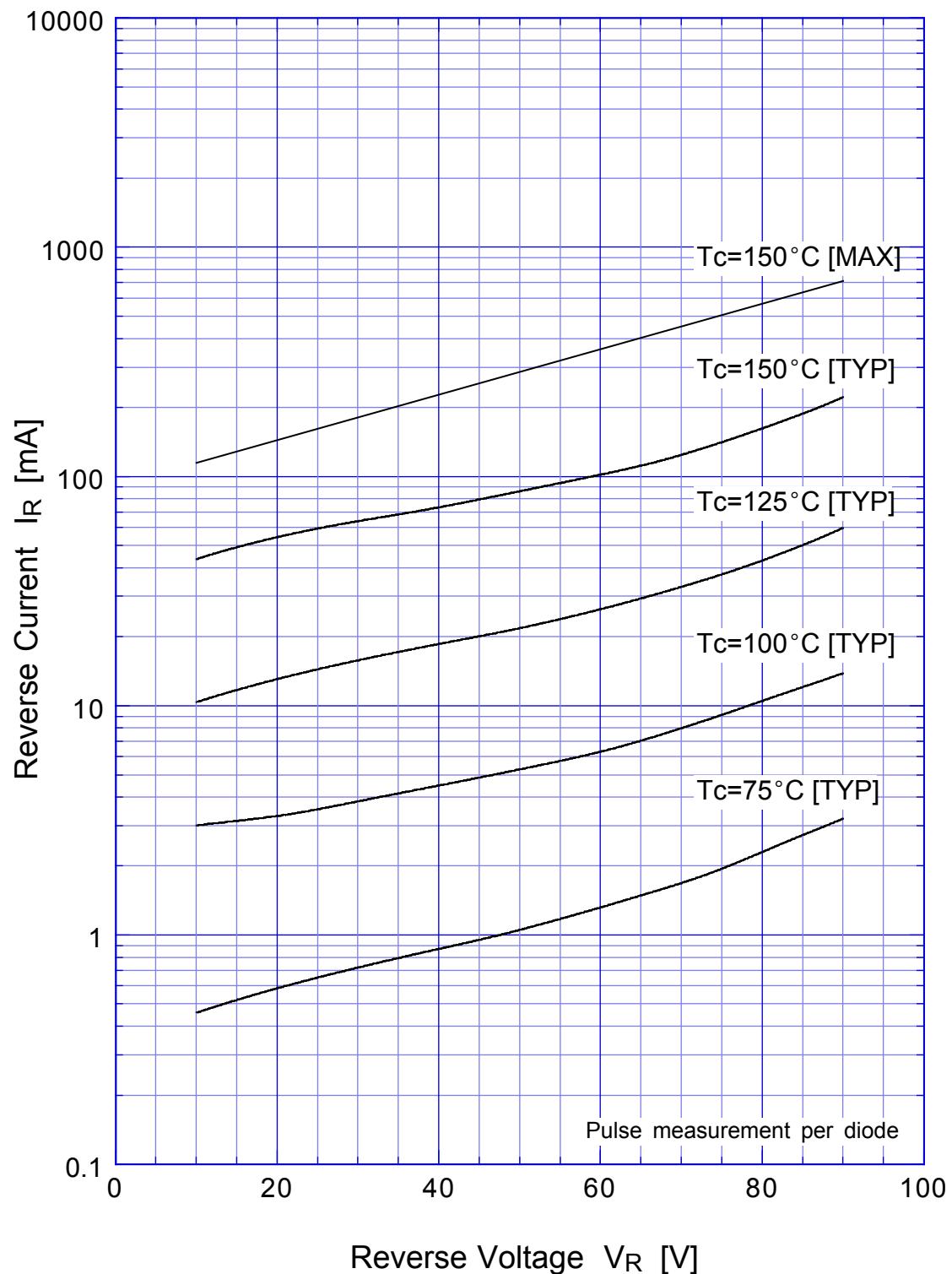




# S20SC9M

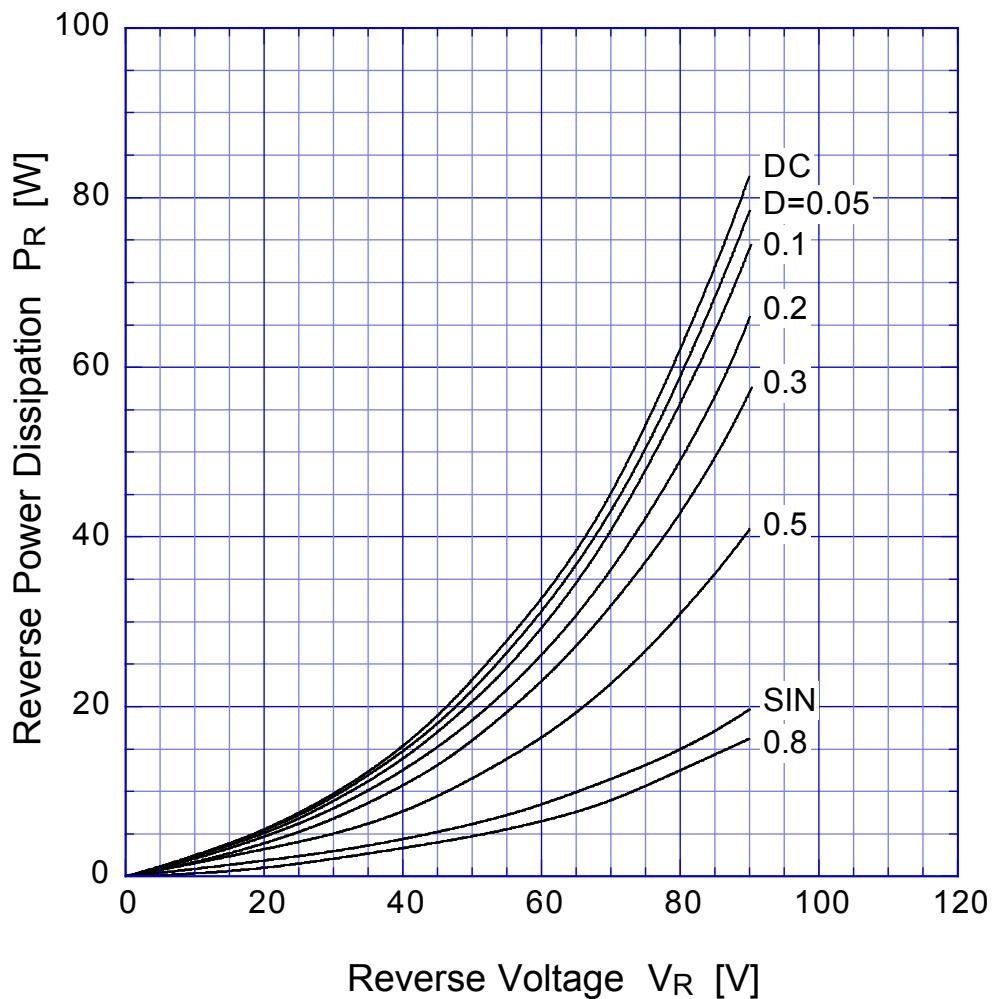
---

## Reverse Current

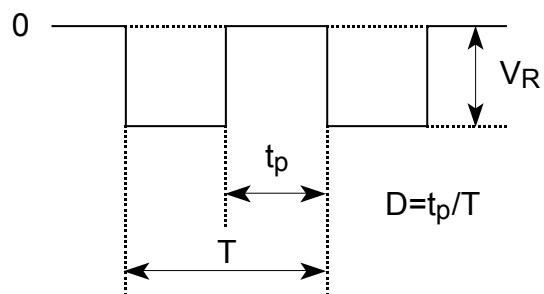


S20SC9M

Reverse Power Dissipation

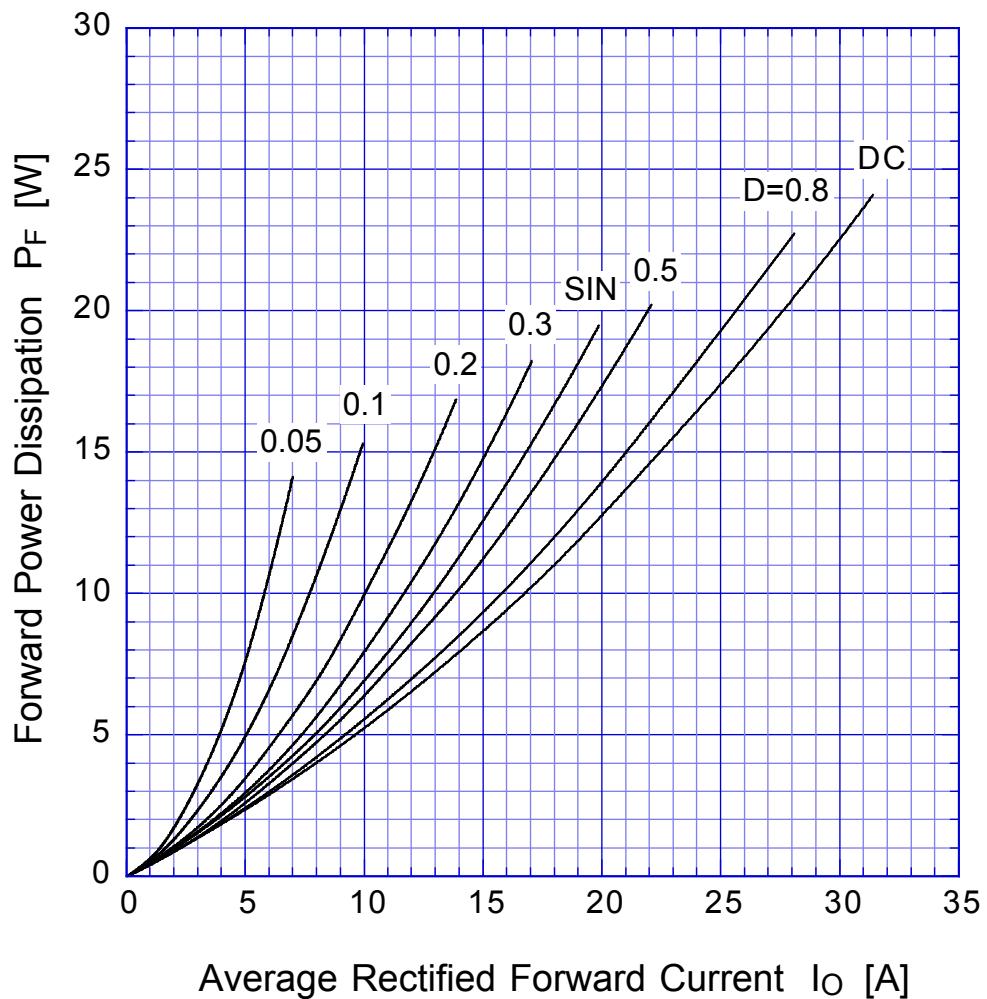


$T_j = 150^\circ\text{C}$

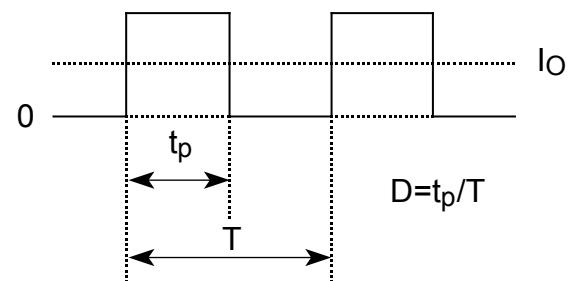


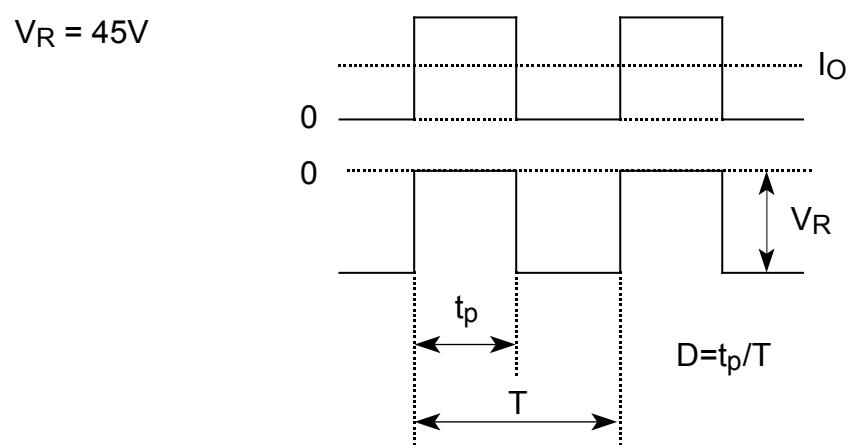
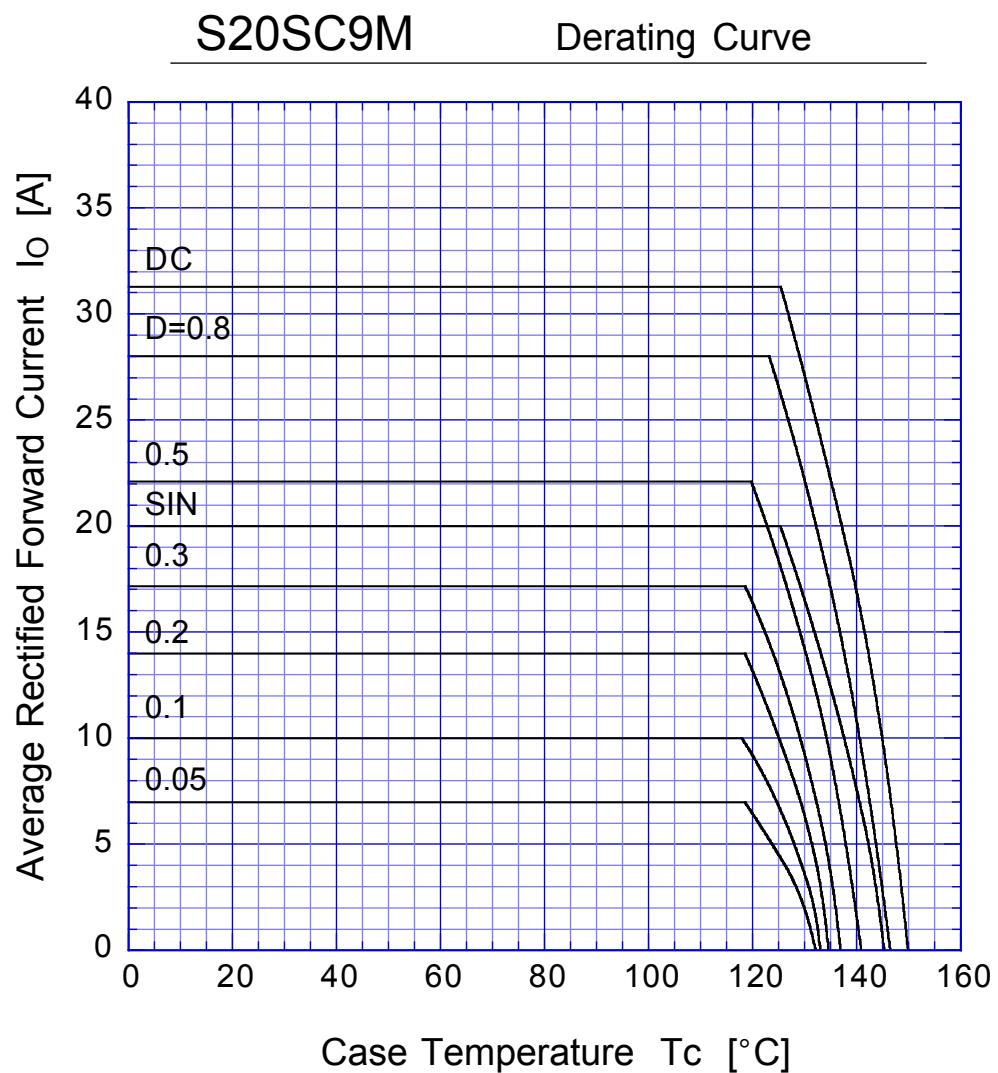
S20SC9M

Forward Power Dissipation

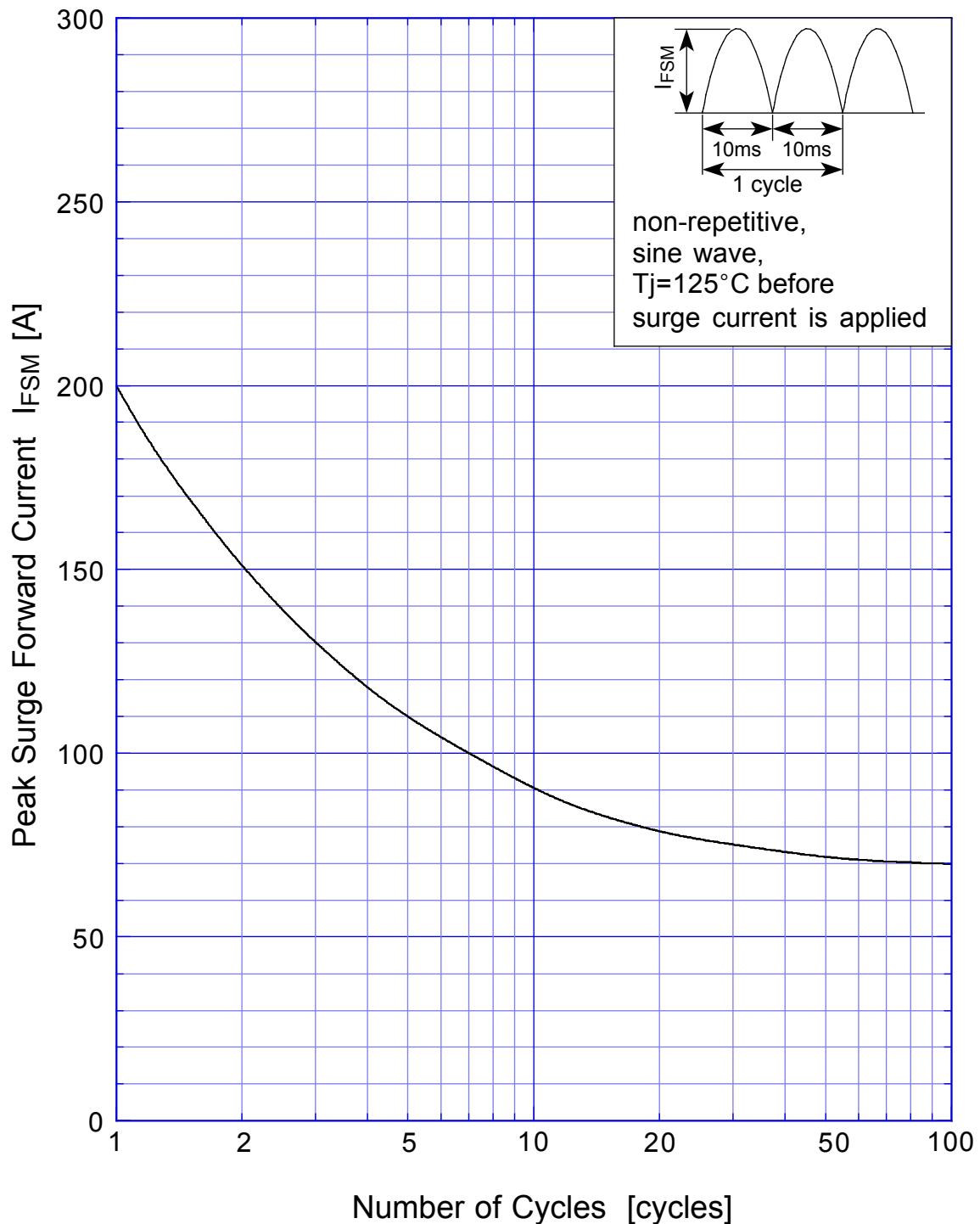


$T_j = 150^\circ\text{C}$





## S20SC9M Peak Surge Forward Capability



## SBD Repetitive Surge Reverse Power Derating Curve



## SBD Repetitive Surge Reverse Power Capability

